

SCHOTTKY BARRIER RECTIFIERS

Reverse Voltage – 20 to 200 Volts

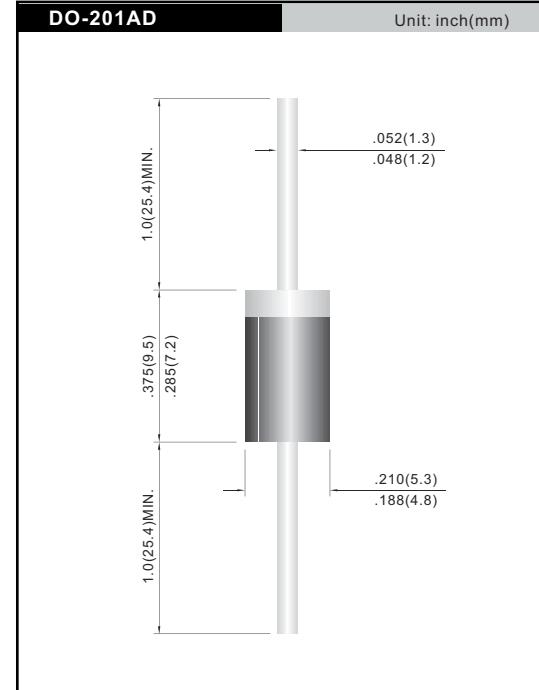
Forward Current – 5.0 Amperes

Features

- Plastic package has Underwriters Laboratory Flammability Classification 94V-0
- Metal silicon junction, majority carrier conduction
- Guard ring for overvoltage protection
- Low power loss, high efficiency
- High current capability, low forward voltage drop
- High surge capability
- For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications
- High temperature soldering guaranteed: 250°C/10 seconds at terminals, 0.375"(9.5mm) lead length, 5lb.(2.3kg) tension

Mechanical Data

- **Case:** Molded plastic body, JEDEC DO-201AD.
- **Terminals:** Axial leads, solderable per MIL-STD-750, method 2026
- **Polarity:** Color band denotes cathode end.
- **Mounting Position:** Any



Absolute Maximum Ratings and Characteristics

Ratings at 25°C ambient temperature unless otherwise specified. Single phase, half wave, resistive or inductive load. For capacitive load, derate by 20%

	Symbols	SR 520	SR 530	SR 540	SR 560	SR 580	SR 5100	SR 5150	SR 5200	Units
Maximum recurrent peak reverse voltage	V _{RRM}	20	30	40	60	80	100	150	200	V
Maximum RMS voltage	V _{RMS}	14	21	28	42	56	70	105	140	V
Maximum DC blocking voltage	V _{DC}	20	30	40	60	80	100	150	200	V
Maximum average forward rectified current 0.375" (9.5mm) lead length	I _(AV)							5.0		A
Peak forward surge current 8.3mS single half sine-wave superimposed on rated load (JEDEC method)	I _{FSM}							150		A
Maximum instantaneous forward voltage at 5 A (Note 1)	V _F			0.55		0.70		0.85		V
Maximum reverse current T _A = 25°C at rated reverse voltage (Note 1) T _A = 100°C	I _R					2.5				mA
				50		25				
Typical junction capacitance (Note 2)	C _{tot}			500			400			pF
Typical thermal resistance, from junction to ambient (Note 3)	R _{θJA}				25					°C/W
Typical thermal resistance, from junction to lead (Note 3)	R _{θJL}				8.0					°C/W
Operating junction temperature range	T _J		-65 to +125			-65 to +150				°C
storage temperature range	T _S				-65 to +150					°C

Notes: (1) Pulse test: 300 μs pulse width, 1% duty cycle

(2) Measured at 1MHz and applied reverse voltage of 4 Volts

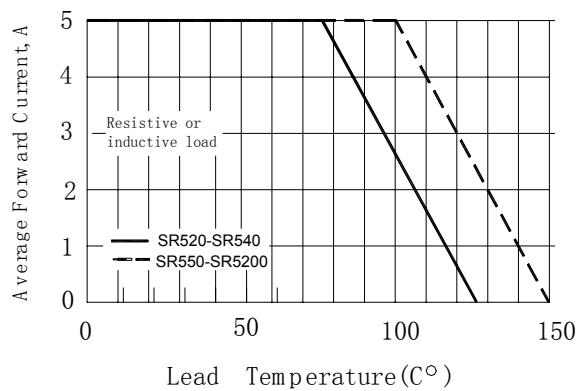
(3) Thermal Resistance from Junction to lead vertical P.C.B, mounted with 0.375"(9.5mm) lead length



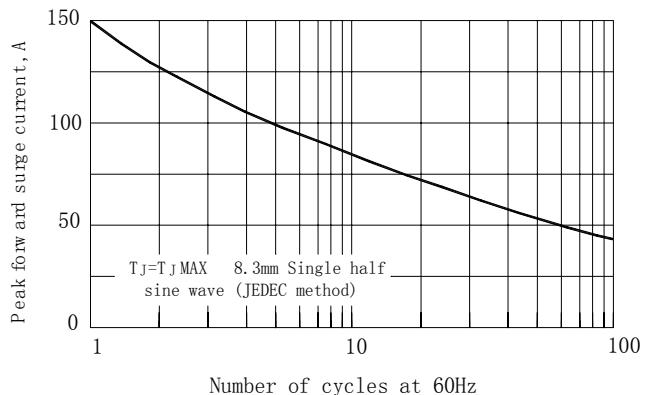
CUMSUMI SEMICONDUCTOR INTERNATIONAL

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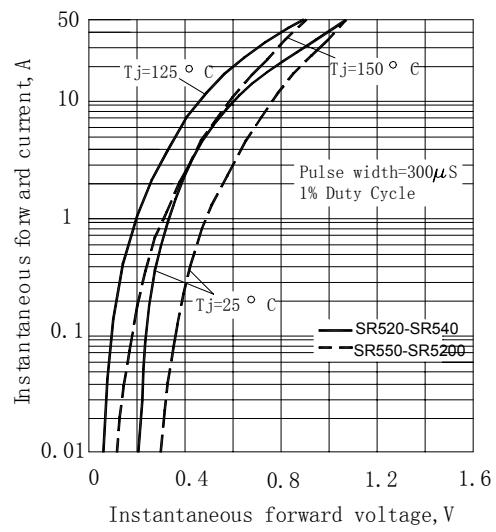
Forward Current Derating Curve



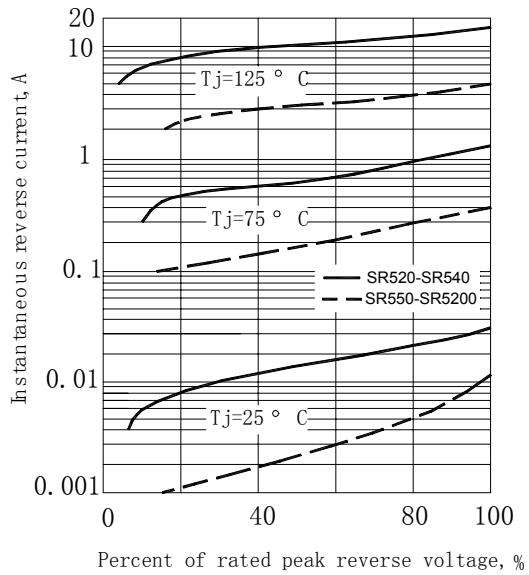
Maximum non-repetitive peak forward surge current



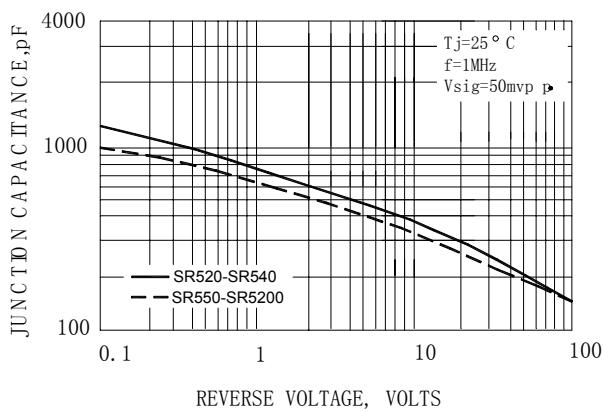
Typical instantaneous forward characteristics



Typical reverse characteristics



TYPICAL JUNCTION CAPACITANCE



TYPICAL TRANSIENT THERMAL IMPEDANCE

